

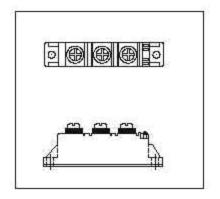
Ruttonsha International Rectifier Ltd.

POWER MODULES

IRK. 105 SERIES High Voltage Diode/Diode

FEATURES

- Electrically isolated base plate.
- 3500 V_{RMS} isolating voltage. Simplified mechanical designs, rapid assembly.
- High surge capability.
- Large creepage distances.
- Aluminum Nitride



DESCRIPTION

These IRK series of Power Modules use power diodes in three basic configurations. The semiconductors are electrically isolated from the metal base, allowing common heatsinks and compact assemblies to be built. They can be interconnected to form single phase or three phase bridges.

These modules are intended for general purpose applications such as battery chargers, welders and plating equipment.

MAJOR RATINGS & CHARACTERISTICS

Parameters		IRK.105	Units	
Lauva	T _c = 87°C	105	А	
F (RMS)	10	164	A	
E SA1	@ 50 Hz	2020	А	
각	@ 50 Hz	20430	A ²s	
) 2 t		204300	A²s	
V RRM	range	400 to 1600	V	
Τ,	range	-40 to 135	"C	

^(*) Contact factory for higher voltages (1600-2000V) and higher currents (60, 80, 100 A)

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ELECTRICAL SPECIFICATION VOLTAGE RATINGS

Type Number	Voltage Code	V _{RRM} , max. repetitive peak reverse voltage V	V _{RSM} , max. non-repetitive peak reverse voltage V	I _{RRM} max. @ Tj = Tj max mA
	04	400	500	10
	06	600	700	10
	08	800	900	10
IRK.105	10	1000	1100	10
	12	1200	1300	10
	14	1400	1500	10
	16	1600	1700	10

FORWARD CONDUCTION

	Parameters	IRK.105	Units	Condition	S
I _{F(AV)}	Max. average forward current	105	А	180°C conduction, half sine wave	
	@ case temperature	87	°C		
I _{F(RMS)}	Max. RMS forward current	164	Α		
 FSM	Max. peak, one cycle forward non-repetitive surge current	2020	А	t = 10ms	
					Sinusodial half wave,
l ² t	Maximum I ² t for fusing	20430	A ² s	t = 10ms	Initial $T_j = T_j$ max.
l ² t	Maximum I ² t for fusing	204300	A 2 s	t = 0.1 to	10ms.
$V_{\text{F(TO)}}$	Threshold Voltage	0.66	V	$T_{J} = T_{J} n$	nax.
r _t	forward slope resistance	1.81	mΩ	$T_{J} = T_{J} \text{ max.}$	
V_{FM}	Max. forward voltage drop	1.34	V	$I_{FM} = \pi \times I_{F(AV)}$, $T_J = 25^{\circ}C$, $t_p = 400 \mu s$ squarewave AV. power = $V_{F(TO)} \times I_{F(AV)} + r_1 \times (I_{F(RMS)})^2$	

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THERMAL AND MECHANICAL SPECIFICATIONS

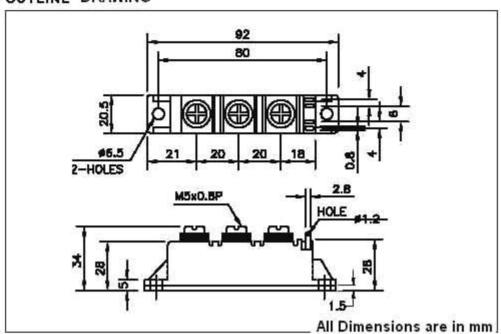
	Parameter	IRK.105	Units	Conditions	
Tj	Junction operating temperature	-40 to 135	°C		
T _{stg}	Storage temperature range	-40 to 150	°C		
R _{thJ-C}	Max. internal thermal resistance, junction to case	0.22	K/W	IRKD/IRKJ/IRKC Per module, DC operation	
R _{thC-S}	Thermal resistance, case to heatsink	0.1	K/W	Mounting surface flat, smooth and greased	
Т	Mounting Module to heatsink torque ±10%	5	Nm	A mounting compound is recommended and the torque should be rechecked after a period of abou 3 hours to allow for the spread of the compound.	
	Busbar to module	3	Nm		
Wt	Approximate weight	115	g		

BLOCKING

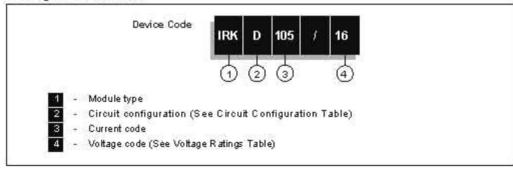
	Parameters	IRK.105	Units	Conditions
I _{RRM}	Max. peak reverse leakage current	10	mA	$T_{\rm J} = 135 {}^{\rm 0}{\rm C}$
V _{INS}	RMS isolation voltage	3500	V	50 Hz circuit to base, all terminals shorted, t = 1s

POWER MODULES

OUTLINE DRAWING



Ordering Information Table



Circuit Configurations Table

